

<b>Notice of References Cited</b>	Application/Control No. 10/669,045	Applicant(s)/Patent Under Reexamination SADOVNIKOV, ALEXEI	
	Examiner Jesse A. Fenty	Art Unit 2815	Page 1 of 1

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**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	King et al., Very Low Cost Graded SiGe Base Bipolar Transistors for a High Performance Modular BiCMOS Process, 1999, IEDM 99, pp. 565-568.
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\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.